



### C Series High Voltage Application

Type:

C4520 [EIA CC1808] C4532 [EIA CC1812]

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TDK MLCC US Catalog

Version A11

### REMINDERS

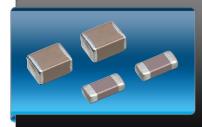
Please read before using this product

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# MULTILAYER CERAMIC CHIP CAPACITORS



## C Series High Voltage Application

Type: C4520, C4532



Advanced design provides improved withstand voltage characteristics.

• TDK's proprietary internal electrode structure and the use of low-dielectric-strength material result in highly reliable performance in high-voltage applications.

- Complies with ISO8802-3 for LAN applications.
- Designed exclusively for reflow soldering.



This product intended solely for reflow soldering.
A slit of about 1mm on the circuit board is recommended to improve removal of the flux after soldering.

- Ensure that this product is completely dried following washing.
- Because this product will be subjected to high voltages, use only low-activity rosin flux (with 0.2% max. of chlorine).

• Using this product with aluminum circuit boards must be considered a special implementation because the high heat stress levels are involved. In case of using aluminum circuit boards, please contact TDK.



### Part Number Construction

<u>C 4532 X7R 3D 222 K T XXXX</u>

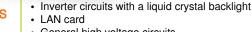
Series Name -		
Dimensions L x	W (mm)	
Case Code	Length	Width
C4520	4.50 ± 0.40	$2.00 \pm 0.30$
C4532	$4.50 \pm 0.40$	$3.20 \pm 0.40$
Temperature Ch	aracteristic	
Temperature	Capacitance	Temperature
Characteristics	Change	Range
C0G	0±30 ppm/ºC	-55 to +125ºC

X7R	±15%	-55 to +125ºC
Datad Valt		

#### Rated Voltage (DC)

Voltage Code	Voltage(DC)	
3A	1,000V	
3D	2,000V	
3F	3,000V	

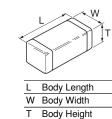
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N DDI D DI D DI	



- General high voltage circuits.
- Noise bypass for power supply
  Transceiver for LAN
- Transceiver for L
  Hub, etc.

В





OVE

B Terminal Width

Dimensions in mm

ĸ		
-	Internal Codes	
-	Packaging Style	
	Packaging Code	Style
	Т	Tape and Reel
-	Capacitance Tole	erance
	Tolerance Code	Tolerance
	F	± 1pF
	K	± 10%

#### Nominal Capacitance (pF)

The capacitance is expressed in three digit codes and in units of pico Farads (pF). The first and second digits identify the first and second significant figures of the capacitance. The third digit identifies the multiplier. R designates a decimal point.

Capacitance Code	Capacitance
0R5	0.5pF
010	1pF
102	1,000pF (1nF)
105	1,000,000pF (1µF)

## MULTILAYER CERAMIC CHIP CAPACITORS



## C4520 [EIA CC1808]

#### Capacitance Range Chart

Temperature Characteristics: C0G (0 ± 30ppm/⁰C), X7R (± 15%) Rated Voltage: 3,000 (3F), 2,000V (3D), 1,000V (3A)

Capacitance	Сар		C0G X7R			
(pF)	Code	Tolerance	3F (3,000V)	3D (2,000V)	3A (1,000V)	
10	100	F: ± 1pF				
12	120	K: ± 10%				
15	150					
18	180					
22	220					
27	270					
33	330					Standard Thickness
39	390					
47	470					
56	560					0.85 ± 0.15 mm
68	680					1.10 ± 0.20 mm
82	820					1.30 ± 0.20 mm
100	101					
470	471					1.60 ± 0.20 mm
1,000	102					2.00 ± 0.20 mm



### Capacitance Range Table

#### Class 1 (Temperature Compensating)

Temperature Characteristics: C0G (0 ± 30 ppm/°C)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4520C0G3F100F	COG	3000V	10	± 1pF	0.85 ± 0.15
C4520C0G3F120K	COG	3000V	12	± 10%	0.85 ± 0.15
C4520C0G3F150K	COG	3000V	15	± 10%	1.10 ± 0.20
C4520C0G3F180K	COG	3000V	18	± 10%	1.10 ± 0.20
C4520C0G3F220K	COG	3000V	22	± 10%	$1.10 \pm 0.20$
C4520C0G3F270K	COG	3000V	27	± 10%	1.60 ± 0.20
C4520C0G3F330K	COG	3000V	33	± 10%	1.60 ± 0.20
C4520C0G3F390K	COG	3000V	39	± 10%	1.60 ± 0.20
C4520C0G3F470K	COG	3000V	47	± 10%	1.60 ± 0.20
C4520C0G3F560K	COG	3000V	56	± 10%	2.00 ± 0.20
C4520C0G3F680K	COG	3000V	68	± 10%	2.00 ± 0.20
C4520C0G3F820K	COG	3000V	82	± 10%	$2.00 \pm 0.20$
C4520C0G3F101K	COG	3000V	100	± 10%	2.00 ± 0.20

#### Class 2 (Temperature Stable)

Temperature Characteristi					
TDK Part Number	Temperature	Rated	Capacitance	Capacitance	Thickness
(Ordering Code)	Characteristics	Voltage	(pF)	Tolerance	(mm)
C4520X7R3A471K	X7R	1000V	470	± 10%	1.30 ± 0.20
C4520X7R3A102K	X7R	1000V	1,000	± 10%	1.30 ± 0.20
C4520X7R3D471K	X7R	2000V	470	± 10%	$1.30 \pm 0.20$
C4520X7R3D102K	X7R	2000V	1,000	± 10%	$1.30 \pm 0.20$

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## MULTILAYER CERAMIC CHIP CAPACITORS



## C4532 [EIA CC1812]

#### Capacitance Range Chart

Temperature Characteristics: C0G (0 ± 30ppm/°C), X7R (± 15%) Rated Voltage: 3,000 (3F), 2,000V (3D), 1,000V (3A)

Capacitance	Сар		COG	X	7R	
(pF)	Code	Tolerance	ЗF	3D	ЗA	
N= - 7			(3,000V)	(2,000V)	(1,000V)	
100	101	K: ± 10%				
120	121					
150	151					Oton doub This was a
180	181					Standard Thickness
220	221					1.30 ± 0.20 mm
270	271					1.60 ± 0.20 mm
330	331					2.00 ± 0.20 mm
2,200	222	]				
4,700	472					2.30 ± 0.20 mm
10,000	103	]				2.50 ± 0.30 mm



Capacitance Range Table

#### Class 1 (Temperature Compensating)

Temperature Characteristics: COG (0 ± 30 ppm/°C)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4532C0G3F101K	COG	3000V	100	± 10%	1.60 ± 0.20
C4532C0G3F121K	COG	3000V	120	± 10%	1.60 ± 0.20
C4532C0G3F151K	COG	3000V	150	± 10%	1.60 ± 0.20
C4532C0G3F181K	COG	3000V	180	± 10%	1.60 ± 0.20
C4532C0G3F221K	COG	3000V	220	± 10%	$2.00 \pm 0.20$
C4532C0G3F271K	COG	3000V	270	± 10%	2.30 ± 0.20
C4532C0G3F331K	COG	3000V	330	± 10%	2.50 ± 0.30

#### Class 2 (Temperature Stable)

Temperature Characteristics: X7R (± 15%)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4532X7R3A472K	X7R	1000V	4,700	± 10%	1.60 ± 0.20
C4532X7R3A103K	X7R	1000V	10,000	± 10%	$2.00 \pm 0.20$
C4532X7R3D222K	X7R	2000V	2,200	± 10%	$1.30 \pm 0.20$

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## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

No.	ltem	Perfor	mance		Test or Inspection Method			
1	External Appearance	No defe perform	ects which mance.	ay affect	Inspect with magnifying glass (3 $ imes$ ).			
2	Insulation Resistance	10,000	$M\Omega$ min.		Apply 500V DC for 60s.			
3	Voltage Proof		and test volta		$1.2 \times$ rated voltage (DC) shall be applied for 1 to 5s. Charge / discharge current shall not exceed 50mA.			
		insulati	on breakdow	n or other damage.				
4	Capacitance	Within the specified tolerance.			Class	Measuring Frequency	Measuring Voltage	
					Class 1	1MHz±10%	0.5 - 5 V <sub>rms</sub>	
					Class 2	1kHz±10%	1.0±0.2V <sub>rms</sub>	
5	Q	Rated CapacitanceQ30pF and over1,000 min.		See No.4 i	n this table for	measuring condition.		
	(Class 1)			1,000 min.				
		Under	30pF	400+20×C min.				
		C : Rated capacitance (pF)						
6	Dissipation	T.C.	D.F.	_	See No.4 i	See No.4 in this table for measuring condition.		
	Factor (Class 2)	X7R 0.03 max.						
7	Temperature			Temperature coefficient shall be calculated based on				
1	Characteristics	T.C.Temperature CoefficientC0G $0 \pm 30 \text{ (ppm/°C)}$ Capacitance drift within $\pm 0.2\%$ or		values at 25°C and 85°C temperature. Measuring temperature below 20°C shall be -10°C ar -25°C.				
	of Capacitance (Class 1)							
		± 0.05pF, whichever larger.						
8	Temperature	Capacitance Change (%)			Capacitance shall be measured by the steps shown in			
	Characteristics	No Voltage Applied       X7R: ± 15%		the following table after thermal equilibrium is obtaine for each step. ΔC be calculated ref. STEP3 reading				
	of Capacitance (Class 2)							
	(01033 2)			Step Temperature (°C)				
					1	Reference temp	<u> </u>	
					2	Min. operating t		
					3	Reference temp		
					4	Max. operating	temp. ± 2	
9	Robustness of Terminations			on coming off, c, or other abnormal			ors on P.C. board (shown in pushing force of 5N with	
					Capac	Pushing force P.C. board		

## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

No.	ltem	Performance			Test or	r Inspection Method			
10	Solderability	New solder to co termination.	over o	over 75% of	Completely soak both terminations in solder at $235\pm5^{\circ}$ C for $2\pm0.5$ s. Solder: H63A (JIS Z 3282)				
		25% may have p	oin ho	les or rough spots					
		but not concentra Ceramic surface not be exposed of shifting of termin	ated of "A due t	Flux: Isopropyl alcohol (JIS K 8839) Rosin (JIS K 5902) 25% solid solution.					
			A see						
11	Vibration					tely soak both terminations	in solder at		
	External appearance	No mechanical c	No mechanical damage.			$C \text{ for } 5 \pm 1 \text{ s.}$			
	Capacitance	Characteristics Change from the value before test		Temp.: 150±10°C Time: 1 to 2min.					
		Class 1 C0G	±2.5 %		Flux: Isc	lux: Isopropyl alcohol (JIS K 8839)			
		Class 2 X7R	±	7.5 %	Ro	osin (JIS K 5902) 25% soli	olid solution.		
	Q (Class 1)	Rated Capacitance Q		Q	Solder: H63A (JIS Z 3282)				
		30pF and over		1,000 min.	Leave th	eave the capacitor in ambient conditions for 6 to 24			
		Under 30pF		400+20×C min.		(1) or 24±2h (Class 2) before measurement.			
		(	C : Ra	ited capacitance (pF)					
	D.F. (Class 2)	Meet the initial s	pec.						
12	Temperature cycle	)			Reflow solder the capacitor on P.C. board (show in Appendix 1) before testing.				
	External appearance	No mechanical c	lama	ge.					
	Capacitance	Characteristics		inge from the ue before test	Expose the capacitor in the conditions step1 through step 4 and repeat 5 times consecutively				
		Class 1 C0G				Leave the capacitor in ambient conditions for $(24h (Class 1) \text{ or } 24\pm 2h (Class 2) \text{ before})$			
		Class 2 X7R	± 7	′.5 %	measu	, , ,			
	Q (Class 1)	Rated Capacitan	се	Q	Step	Temperature (ºC)	Time (min.)		
		30pF and over		1,000 min.	1	Min. operating temp. ±3	30 ± 3		
		Under 30pF		400+20×C min.	2		2-5		
		C : Rat		ited capacitance (pF)	3	Max. operating temp. $\pm$ 2	30 ± 2		
	D.F. (Class 2)	Meet the initial spec.			4	Reference Temp.	2 - 5		
	Insulation Resistance		Meet the initial spec.						
	Voltage Proof	No insulation breakdown or other damage.							

• All specifications are subject to change without notice. Please read the precautions before using the product.

General Specifications

## MULTILAYER CERAMIC CHIP CAPACITORS

## C Series – High Voltage Application

No.	ltem	Performa	ance		Test or Inspection Method	
13	Moisture Resist	ance (Steady No mecha	-	nage.	Reflow solder the capacitors on P.C. board (shown in Appendix 1) before testing. Leave at temperature $40\pm 2^{\circ}$ C, 90 to 95%RH for 500	
	appearance Capacitance			Change from the value before test	<ul> <li>+24,0h.</li> <li>Leave the capacitors in ambient conditions for 6 to 24h</li> </ul>	
		Class 1	C0G	±5 %	(Class 1) or 24 $\pm$ 2h (Class 2) before measurement.	
		Class 2	X7R	±12.5 %		
	Q (Class 1)	Rated Car	acitance	Q	_	
		30pF and		350 min.		
		10pF and under 30p	over to	275+5/2×C min.		
				ated capacitance (pF)		
	D.F. (Class 2)	Character X7R: 2009		Il spec. max.		
	Insulation Resistance	1,000MΩ min.			_	
14	Life				Reflow solder the capacitors on P.C. board (shown in	
	External appearance	No mecha	inical dar	nage.	Appendix 1) before testing. Apply rated voltage at maximum operating temperature	
	··-				$- \pm 2^{\circ}$ C for 1,000 +48, 0h.	
	Capacitance			Change from the value before test	Charge/discharge current shall not exceed 50mA.	
		Class 1	C0G	±3 %	Leave the capacitor in ambient conditions for 6 to 24h	
		Class 2	X7R	±15 %	(Class1) or 24±2h (Class2) before measurement.	
	Q (Class 1)	Rated Cap	pacitance	Q	<ul> <li>Voltage conditioning:</li> <li>Voltage treat the capacitors under testing temperature</li> </ul>	
	, , , , , , , , , , , , , , , , , , ,	30pF and		350 min.	and voltage for 1 hour.	
		10pF and under 30p		275+5/2×C min.	Leave the capacitors in ambient conditions for $24\pm 2h$ before measurement.	
			C : Ra	ated capacitance (pF)		
	D.F. (Class 2)	Character X7R: 2009		Il spec. max.	<ul> <li>Use this measurement for initial value.</li> </ul>	
	Insulation Resistance	1,000M Ω			_	

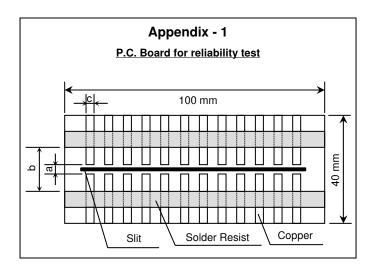
\*As for the initial measurement of capacitors (Class 2) on number 8, 11, 12 and 13, leave capacitors at 150–10, 0°C for 1 hour and measure the value after leaving capacitor for 24±2h in ambient condition.

## MULTILAYER CERAMIC CHIP CAPACITORS



General Specifications

## C Series – High Voltage Application



Material : Glass Epoxy (As per JIS C6484 GE4)

P.C. Board thickness: 1.6mm

Copper (thickness 0.035mm) Solder resist

Case	Code	Di	mensions (m	m)
JIS	EIA	а	b	С
C4520	CC1808	3.5	7.0	2.5
C4532	CC1812	3.5	7.0	3.7

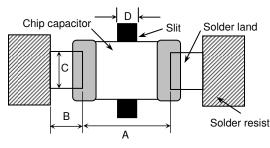
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## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

### Recommended Soldering Land Pattern



· This product intended solely for reflow soldering.

A slit of about 1mm on the circuit board is
recommended to improve removal of the flux after

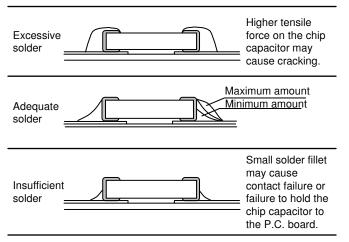
soldering.Ensure that this product is completely dried following washing.

Because this product will be subjected to high voltages, use only low-activity rosin flux (with 0.2% max.

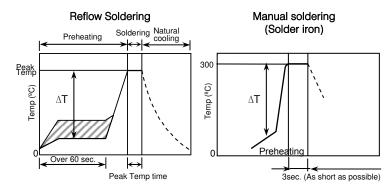
of chlorine). • Using this product with aluminum circuit boards must be considered a special implementation because the high heat stress levels are involved. In case of using aluminum circuit boards, please contact TDK.

Reflow Solde	Unit: mm		
Туре	C4520	C4532	
Symbol	[CC1808]	[CC1812]	
А	3.1 – 3.7	3.1 – 3.7	
В	1.2 – 1.4	1.2 – 1.4	
С	1.5 - 2.0	2.4-3.2	
D	1.0 - 1.3	1.0 - 1.3	

#### • Recommended Solder Amount



### • Recommended Soldering Profile



#### **Recommended soldering duration**

Temp./	<b>Reflow Soldering</b>		
Dura. Solder	Peak temp (°C)	Duration (sec.)	
Sn-Pb Solder	230 max.	20 max.	
Lead-Free Solder	260 max.	10 max.	

Recommended solder compositions Sn-37Pb (Sn-Pb solder) Sn-3.0Ag-0.5Cu (Lead Free Solder)

#### **Preheating Condition**

Soldering	Temp. (ºC)
Reflow soldering	∆T ≤ 130
Manual soldering	∆T ≤ 130

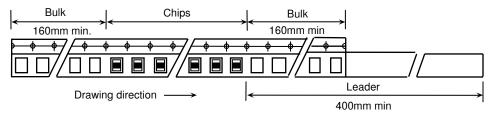
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## MULTILAYER CERAMIC CHIP CAPACITORS

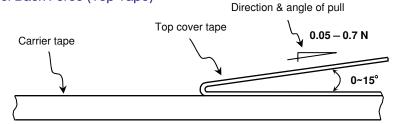


## C Series – High Voltage Application

### Carrier Tape Configuration



• Peel Back Force (Top Tape)

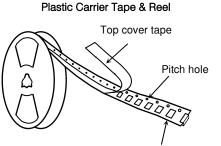


• Carrier tape shall be flexible enough to be wound around a minimum radius of 30mm with components in tape.

 $\bullet$  The missing of components shall be less than 0.1%

Components shall not stick to the cover tape.
The cover tape shall not protrude beyond the edges of the carrier tape not shall cover the sprocket holes.

### Chip Quantity Per Reel and Structure of Reel



Plastic carrier tape

Case	e Code	Ohim	<b>T</b>	Chip quantity (pcs.)		
JIS	EIA	Chip Thickness	Taping Material	φ178mm (7") reel	Ф330mm (13") reel	
		0.85 mm				
	CC1808	1.10 mm	Plastic		5,000	
C4520		1.30 mm		1,000		
		1.60 mm			3,000	
		2.00 mm			3,000	
	CC1812	1.30 mm	-		5,000	
		1.60 mm		1,000		
C4532		2.00 mm	Plastic		0.000	
		2.30 mm		500	3,000	
		3.20 mm		500		

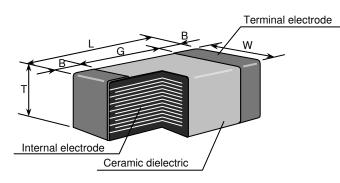
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## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

• Shape & Dimensions



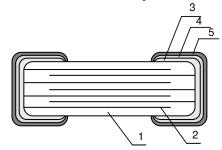
Cas	e Code	Dimensions (mm)					
				0.85 mm	0.30 min		
				1.10 mm	0.30 11111		
C4520	CC1808	4.50	2.00	1.30 mm	2.00 min	2.00 min	
				1.60 mm	0.30 min		
				2.00 mm			
	CC1812	CC1812 4.50	3.20	1.30 mm	0.30 min.		
				1.60 mm	0.20 min	2.00 min	
C4532				2.00 mm			
				2.30 mm			
				3.20 mm	0.30 min.		

#### Environmental Information

TDK Corporation established internal product environmental assurance standards that include the six hazardous substances banned by the EU RoHS Directive<sup>1</sup> enforced on July 1, 2006 along with additional substances independently banned by TDK and has successfully completed making general purpose electronic components conform to the RoHS Directive<sup>2</sup>.

- Abbreviation for Restriction on Hazardous Substances, which refers to the regulation EU Directive 2002/95/EC on hazardous substances by the European Union (EU) effective from July 1, 2006. The Directive bans the use of six specific hazardous substances in electric and electronic devices and products handled within the EU. The six substances are lead, mercury, cadmium, hexavalent chromium, PBB (polybrominated biphenyls), and PBDE (polybrominated diphenyl ethers).
- This means that, in conformity with the EU Directive 2002/95/EC, lead, cadmium, mercury, hexavalent chromium, and specific bromine-based flame retardants, PBB and PBDE, have not been used, except for exempted applications.
- For REACH (SVHC : 15 substances according to ECHA / October 2008) : All TDK MLCC do not contain these 15 substances.
- For European Directive 2000/53/CE and 2005/673/CE : Cadmium, Hexavalent Chromium, Mercury, Lead are not contained in all TDK MLCC.
- For European Directive 2003/11/CE : Pentabromodiphenyl-ether, Octabromodiphenyl-ether are not contained in all TDK MLCC.
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Inside Structure & Material System



No.	NAME	MATERIAL			
		Class 1	Class 2		
(1)	Ceramic Dielectric	CaZrO <sub>3</sub>	BaTiO₃		
(2)	Internal Electrode	Nickel (Ni)			
(3)		Coppe	er (Cu)		
(4)	Termination	Nickel (Ni)			
(5)		Tin (Sn)			